

Trans IGBT Chip N-CH 3000V 80A 400mW 3-Pin(3+Tab) TO-247AD

Manufacturer: <u>Littelfuse Inc</u>

Package/Case: TO-247

Product Type: Thyristors

Lifecycle: Active Images are for reference only

Inquiry

General Description

BiMOSFETs are devices, which have combined strengths of MOSFETs and IGBTs. Non-epitaxial construction and new fabrication processes were used in making BiMOSFETs a great success. These high voltage devices are ideal for parallel operation due to the positive voltage temperature coefficient of both of its saturation voltage, and the forward voltage drop of its intrinsic diode. Furthermore, this "free" intrinsic body diode serves as a protection diode, providing an alternative path for the inductive load current during device turn-off, preventing high Ldi/dt voltage transients from inflicting damage to the device.

Key Features Application High power density Switched-mode and resonant-mode power supplies High frequency operation Uninterruptible Power Supplies (UPS) Low conduction losses Laser and X-ray generators MOS gate turn on for drive simplicity Capacitor discharge circuits 4000V electrical isolation High voltage pulser circuits Advantages: Low gate drive requirements High voltage test equipment Space savings (eliminates multiple series-parallel lower voltage, lower current rated devices) AC switches Easy to mount

Recommended For You

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TO-247 MODULE TO-247

IXGP20N120A3 IXYR50N120C3D1 IXYH50N65C3D1

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TO-220 ISOPLUS247 TO-247

IXGP8N100 IXTQ460P2 IXGR48N60C3D1

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